SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

- Open Drain Power-On Reset With 220-ms Delay (TPS771xx)
- Open Drain Power-Good (PG) Status Output (TPS772xx)
- 150-mA Low-Dropout Voltage Regulator
- Available in 1.5-V, 1.8-V, 2.7-V, 2.8-V, 3.3-V, 5.0-V Fixed Output and Adjustable Versions
- **Dropout Voltage Typically 115 mV** at 150 mA (TPS77133, TPS77233)
- Ultralow 92-µA Quiescent Current (Typ)
- 8-Pin MSOP (DGK) Package
- Low Noise (55 μV_{rms}) Without External Filter (Bypass) Capacitor (TPS77118, **TPS77218)**
- 2% Tolerance Over Specified Conditions for Fixed-Output Versions
- **Fast Transient Response**
- **Thermal Shutdown Protection**

description

The TPS771xx and TPS772xx are low-dropout regulators with integrated power-on reset and power good (PG) function respectively. These devices are capable of supplying 150 mA of output current with a dropout of 115 mV (TPS77133, TPS77233). Quiescent current is 92 µA at full load dropping down to 1 μA when device is disabled. These devices are optimized to be stable with a wide range of output capacitors including low ESR ceramic (10 μ F) or low capacitance (1 μ F) tantalum capacitors. These devices have extremely low noise output performance (55 µV_{rms}) without using any added filter capacitors. TPS771xx and TPS772xx are designed to have fast transient response for larger load current changes.

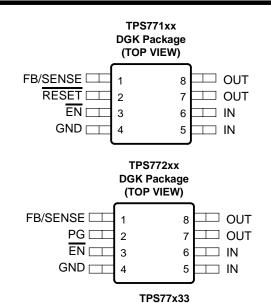
The TPS771xx or TPS772xx is offered in 1.5 V,

1.8-V, 2.7-V, 2.8-V, 3.3-V, and 5.0 V fixed-voltage versions and in an adjustable version (programmable over the range of 1.5 V to 5.5 V). Output voltage tolerance is 2% over line, load, and temperature ranges. The TPS771xx and TPS772xx families are available in 8-pin MSOP (DGK) packages.

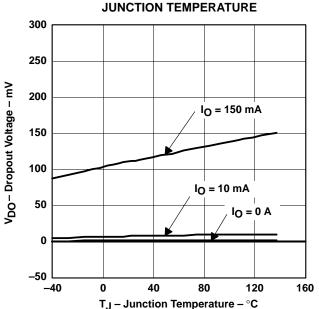
Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 115 mV at an output current of 150 mA for 3.3 volt option) and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 92 μA over the full range of output current, 0 mA to 150 mA). These two key specifications yield a significant improvement in operating life for battery-powered systems.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



DROPOUT VOLTAGE



PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright @ 2000, Texas Instruments Incorporated

Adjustable

1.5 V to 5.5 V

SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

description (continued)

The device is enabled when the \overline{EN} pin is connected to a low-level input voltage. This LDO family also features a sleep mode; applying a TTL high signal to \overline{EN} (enable) shuts down the regulator, reducing the quiescent current to less than 1 μA at $T_{,1} = 25^{\circ} C$.

The TPS771xx features an integrated power-on reset, commonly used as a supply voltage supervisor (SVS) or reset output voltage. The RESET output of the TPS771xx initiates a reset in DSP, microcomputer or microprocessor systems at power up and in the event of an undervoltage condition. An internal comparator in the TPS771xx monitors the output voltage of the regulator to detect an undervoltage condition on the regulated output voltage. When OUT reaches 95% of its regulated voltage, RESET will go to a high-impedance state after a 220 ms delay. RESET will go to low-impedance state when OUT is pulled below 95% (i.e. over load condition) of its regulated voltage.

For the TPS772xx, the power good terminal (PG) is an active high output, which can be used to implement a power-on reset or a low-battery indicator. An internal comparator in the TPS772xx monitors the output voltage of the regulator to detect an undervoltage condition on the regulated output voltage. When OUT falls below 82% of its regulated voltage, PG will go to a low-impedance state. PG will go to a high-impedance state when OUT is above 82% of its regulated voltage.

OUTPUT VOLTAGE PACKAGED DEVICES MSOP (DGK) (V) TJ TPS771xx TPS772xx TYP SYMBOL SYMBOL 5.0 TPS77150DGK **AFV** TPS77250DGK **AGE** AFU AGD 3.3 TPS77133DGK TPS77233DGK 2.8 TPS77128DGK **AFS** TPS77228DGK AGB 2.7 TPS77127DGK **AFR** TPS77227DGK AGA -40°C to 125°C 1.8 TPS77118DGK **AFP** TPS77218DGK **AFY** 1.5 TPS77115DGK AFO TPS77215DGK **AFX**

AVAILABLE OPTIONS

NOTE: The TPS77101 and TPS77201 are programmable using an external resistor divider (see application information). The DGK package is available taped and reeled. Add an R suffix to the device type (e.g., TPS77101DGKR).

AFN

TPS77201DGK

AFW

TPS77101DGK

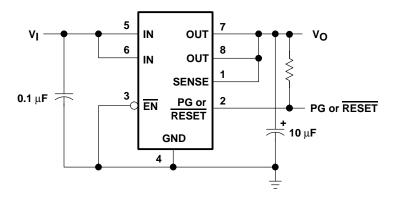


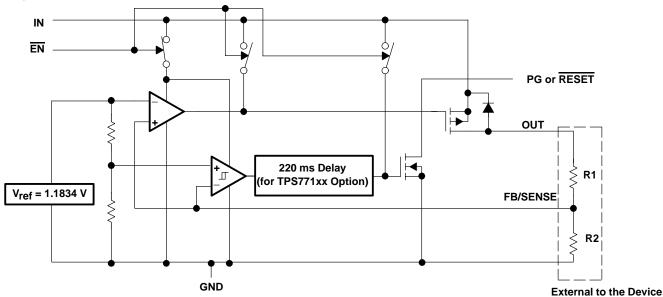
Figure 1. Typical Application Configuration (For Fixed Output Options)



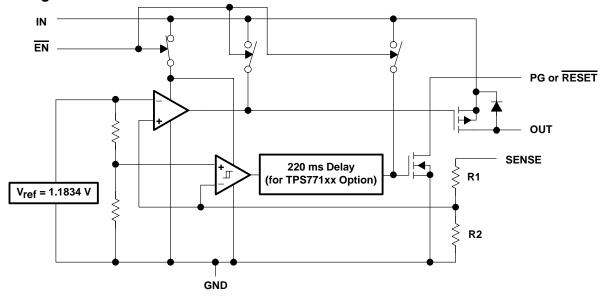
SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

functional block diagrams

adjustable version



fixed-voltage version

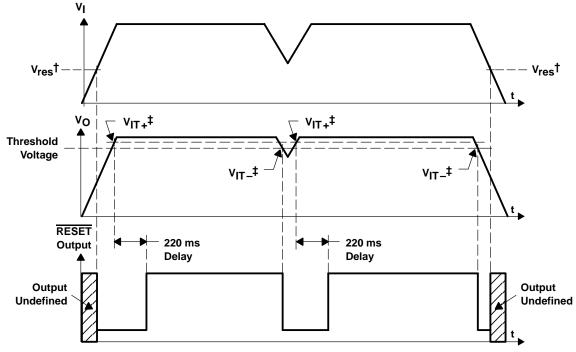


SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

Terminal Functions

TERMIN	AL	1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
TPS771XX			
FB/SENSE	1	ı	Feedback input voltage for adjustable device (sense input for fixed options)
RESET	2	0	Reset output
EN	3	I	Enable input
GND	4		Regulator ground
IN	5, 6	I	Input voltage
OUT	7, 8	0	Regulated output voltage
TPS772XX			
FB/SENSE	1	ı	Feedback input voltage for adjustable device (sense input for fixed options)
PG	2	0	Power good
EN	3	I	Enable input
GND	4		Regulator ground
IN	5, 6	I	Input voltage
OUT	7, 8	0	Regulated output voltage

TPS771xx RESET timing diagram



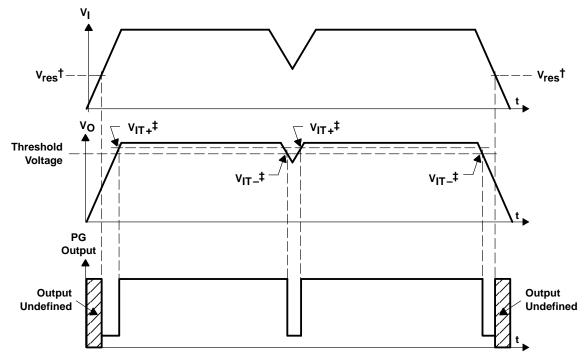
[†] V_{res} is the minimum input voltage for a valid RESET. The symbol V_{res} is not currently listed within EIA or JEDEC standards for semiconductor symbology.

‡ V_{IT} – Trip voltage is typically 5% lower than the output voltage (95%V_O) V_{IT} to V_{IT} is the hysteresis voltage.



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

TPS772xx PG timing diagram



[†] V_{res} is the minimum input voltage for a valid PG. The symbol V_{res} is not currently listed within EIA or JEDEC standards for semiconductor symbology.

absolute maximum ratings over operating junction temperature range (unless otherwise noted)†

Input voltage range, V _I , (see Note 1)	$\ldots \ldots -0.3$ V to 13.5 V
Voltage range at EN	0.3 V to 16.5 V
Maximum RESET voltage (TPS771xx)	16.5 V
Maximum PG voltage (TPS772xx)	16.5 V
Peak output current	Internally limited
Continuous total power dissipation	See Dissipation Rating Table
Continuous total power dissipation	
·	5.5 V
Output voltage, VO (OUT, FB)	5.5 V –40°C to 125°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network terminal ground.



[‡] V_{IT} − Trip voltage is typically 18% lower than the output voltage (82%V_O) V_{IT} to V_{IT+} is the hysteresis voltage.

SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

DISSIPATION RATING TABLE - FREE-AIR TEMPERATURES

PACKAGE	AIR FLOW (CFM)	θJA (°C/W)	θJC (°C/W)	T _A < 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
	0	266.2	3.84	376 mW	3.76 mW/°C	207 mW	150 mW
DGK	150	255.2	3.92	392 mW	3.92 mW/°C	216 mW	157 mW
	250	242.8	4.21	412 mW	4.12 mW/°C	227 mW	165 mW

recommended operating conditions

	MIN	MAX	UNIT
Input voltage, V _I †	2.7	10	V
Output voltage range, VO	1.5	5.5	V
Output current, I _O (see Note 2)	0	150	mA
Operating virtual junction temperature, T _J (see Note 2)	-40	125	°C

[†] To calculate the minimum input voltage for your maximum output current, use the following equation: $V_{I(min)} = V_{O(max)} + V_{DO(max load)}$. NOTE 2: Continuous current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

electrical characteristics over recommended operating junction temperature range (–40°C to 125°C), $V_I = V_{O(typ)} + 1 \text{ V}$, $I_O = 1 \text{ mA}$, $\overline{EN} = 0 \text{ V}$, $C_O = 10 \mu\text{F}$ (unless otherwise noted)

PARAMETE	र	TEST CO	ONDITIONS	MIN	TYP	MAX	UNIT		
		$1.5 \text{ V} \le \text{V}_{\text{O}} \le 5.5 \text{ V},$	T _J = 25°C		٧o		.,		
	Adjustable voltage	$1.5 \text{ V} \le \text{V}_{\text{O}} \le 5.5 \text{ V}$		0.98V _O		1.02V _O	V		
	4.5.V.Outroit	T _J = 25°C,	2.7 V < V _{IN} < 10 V		1.5				
	1.5-V Output	2.7 V < V _{IN} < 10 V		1.470		1.530			
	1.9.V.Output	T _J = 25°C,	2.8 V < V _{IN} < 10 V		1.8				
	1.8-V Output	$2.8 \text{ V} < \text{V}_{1N} < 10 \text{ V}$		1.764		1.836			
Output voltage	2.7-V Output	T _J = 25°C,	3.7 V < V _{IN} < 10 V		2.7		V		
(see Notes 3 and 4)	2.7-v Output	3.7 V < V _{IN} < 10 V		2.646		2.754	V		
	2.8-V Output	T _J = 25°C,	$3.8 \text{ V} < \text{V}_{1N} < 10 \text{ V}$		2.8				
	2.0-v Output	3.8 V < V _{IN} < 10 V		2.744		2.856			
	3.3-V Output	T _J = 25°C,	$4.3 \text{ V} < \text{V}_{1N} < 10 \text{ V}$		3.3				
	3.5-v Output	4.3 V < V _{IN} < 10 V		3.234		3.366			
	5.0-V Output	$T_J = 25^{\circ}C$,	6 V < V _{IN} < 10 V		5.0		V		
3.0-v Output		6 V < V _{IN} < 10 V		4.900		5.100	V		
Quiescent current (GND current)	(see Notes 3 and 4)	T _J = 25°C			92		μА		
Quiescent current (OND current)	(SCC NOTCS O and 4)					125	·		
Output voltage line regulation (ΔV	(see Note 5)	$V_{O} + 1 V < V_{I} \le 10 V$	T _J = 25°C		0.005		%/V		
	0,10, (888) 1818 3,	V _O + 1 V < V _I ≤ 10 V				0.05	%/V		
Load regulation		T _J = 25°C			1		mV		
Output noise voltage		BW = 300 Hz to 100 k TPS77118, TPS77218			55		μVrms		
Output current Limit		V _O = 0 V			0.9	1.3	Α		
Peak output current		2 ms pulse width,	50% duty cycle		400		mA		
Thermal shutdown junction temporal	erature				144		°C		
Standby current		EN = V _I ,	T _J = 25°C			1	μΑ		
		EN = V _I				3	μΑ		
FB input current	Adjustable voltage	FB = 1.5 V				1	μΑ		
High level enable input voltage				2			V		
Low level enable input voltage						0.7	V		
Enable input current				-1		1	μΑ		
Power supply ripple rejection (TP	S77118, TPS77218)	f = 1 KHz,	T _J = 25°C		55		dB		

NOTES: 3. Minimum input operating voltage is 2.7 V or V_{O(typ)} + 1 V, whichever is greater. Maximum input voltage = 10 V, minimum output current 1 mA.

4. If $V_O < 1.8 \text{ V then } V_{I(max)} = 10 \text{ V}, V_{I(min)} = 2.7 \text{ V}$:

Line regulation (mV) =
$$(\%/V) \times \frac{V_O(V_{I(max)} - 2.7 V)}{100} \times 1000$$

If $V_O > 2.5 \text{ V then } V_{I(max)} = 10 \text{ V}, V_{I(min)} = V_O + 1 \text{ V}$:

Line regulation (mV) =
$$(\%/V) \times \frac{V_O(V_{I(max)} - (V_O + 1))}{100} \times 1000$$

5. $I_O = 1 \text{ mA to } 150 \text{ mA}$



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

electrical characteristics over recommended operating junction temperature range (–40°C to 125°C), $V_I = V_{O(typ)} + 1 V$, $I_O = 1 \text{ mA}$, $\overline{EN} = 0 V$, $C_O = 10 \,\mu\text{F}$ (unless otherwise noted) (continued)

	PARAMETER		TEST	CONDITIONS	MIN	TYP	MAX	UNIT
	Minimum input voltage for valid I	PG	$I_{(PG)} = 300 \mu A$	V _(PG) ≤ 0.8 V		1.1		V
	Trip threshold voltage		V _O decreasing		79		85	%VO
PG (TPS772xx)	Hysteresis voltage		Measured at Vo)		0.5		%VO
(11 0772xx)	Output low voltage		V _I = 2.7 V,	I(PG) = 1mA		0.15	0.4	V
	Leakage current		V _(PG) = 5 V				1	μΑ
	Minimum input voltage for valid	RESET	I _(RESET) = 300) μΑ		1.1		V
	Trip threshold voltage		V _O decreasing		92		98	%VO
Reset	Hysteresis voltage		Measured at Vo)		0.5		%Vo
(TPS771xx)	Output low voltage		V _I = 2.7 V,	I(RESET) = 1 mA		0.15	0.4	V
	Leakage current		V(RESET) = 5			1	μΑ	
	RESET time-out delay					220		ms
		0.0.1/ Outmot	I _O = 150 mA,	T _J = 25°C		150		
		2.8-V Output	I _O = 150 mA,				265	
	Donata de la contra de la Nata (N	0.0.1/ 0	I _O = 150 mA,	T _J = 25°C		115		
VDO	Dropout voltage (see Note 6)	3.3-V Output	I _O = 150 mA				200	mV
		E O V Output	I _O = 150 mA,	T _J = 25°C		75		
		5.0-V Output	I _O = 150 mA	_		•	115	

NOTE 6: IN voltage equals V_O(typ) – 100 mV; 1.5 V, 1.8 V, and 2.7 V dropout voltage limited by input voltage range limitations (i.e., 3.3 V input voltage needs to drop to 3.2 V for purpose of this test).

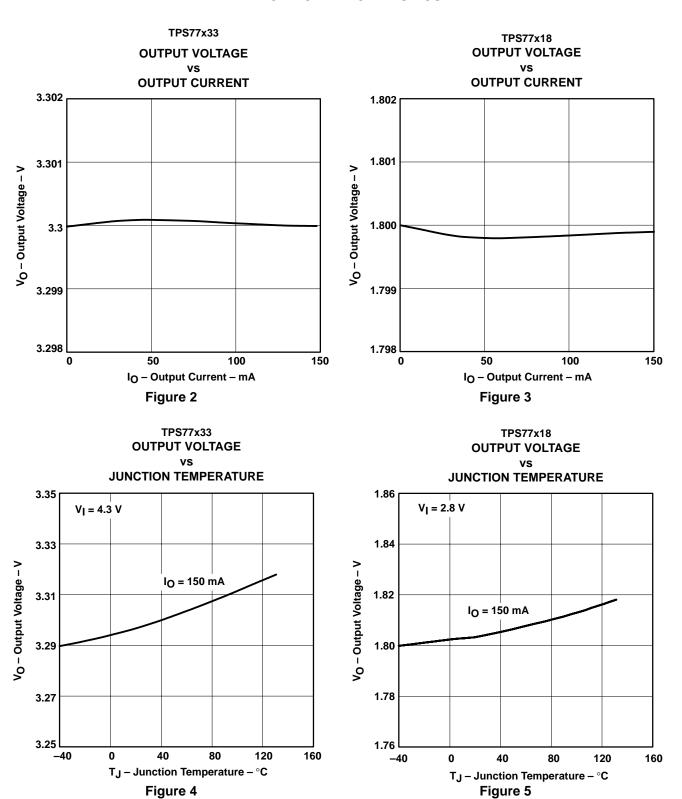
TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
	Q !·	vs Output current	2, 3
VO	Output voltage	vs Junction temperature	4, 5
	Ground current	vs Junction temperature	6
	Power supply rejection ratio	vs Frequency	7
	Output spectral noise density	vs Frequency	8
Z _O	Output impedance	vs Frequency	9
	5	vs Input voltage	10
VDO	Dropout voltage	vs Junction temperature	11
	Line transient response		12, 14
	Load transient response		13, 15
	Output voltage and enable pulse	vs Time	16
	Equivalent series resistance (ESR)	vs Output current	18 – 21

SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

TYPICAL CHARACTERISTICS



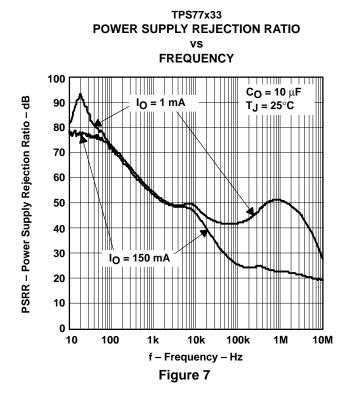


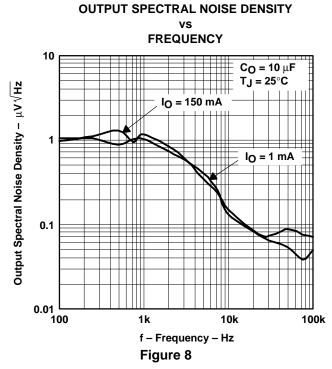
TYPICAL CHARACTERISTICS

TPS77xxx **GROUND CURRENT JUNCTION TEMPERATURE** 115 110 $I_0 = 150 \text{ mA}$ 105 Ground Current - µA 100 95 I_O = 1 mA 90 85 80 10 60 110 160 -40

Figure 6

T_J - Junction Temperature - °C





TPS77x33



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

TYPICAL CHARACTERISTICS

TPS77x33 OUTPUT IMPEDANCE VS EREQUENCY

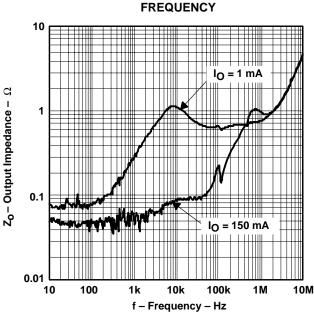
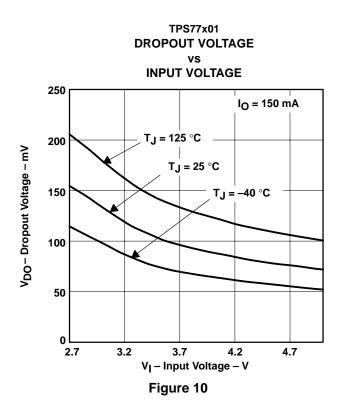
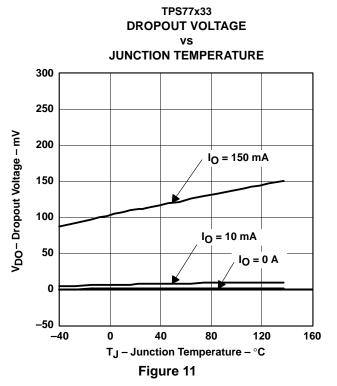


Figure 9





TYPICAL CHARACTERISTICS

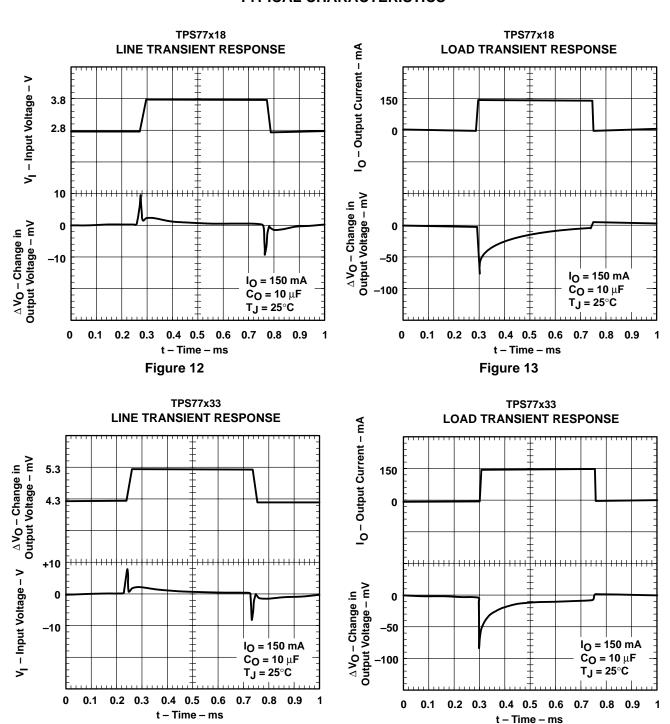




Figure 15

Figure 14

SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

TYPICAL CHARACTERISTICS

TPS77x33 OUTPUT VOLTAGE AND ENABLE PULSE

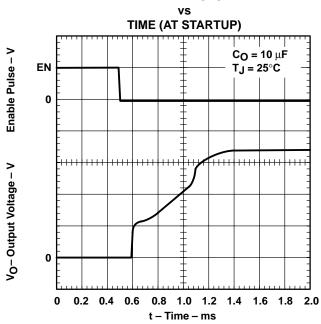


Figure 16

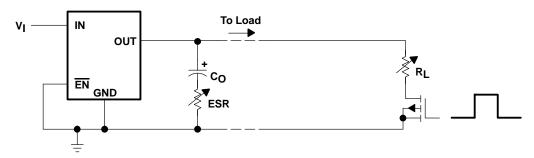
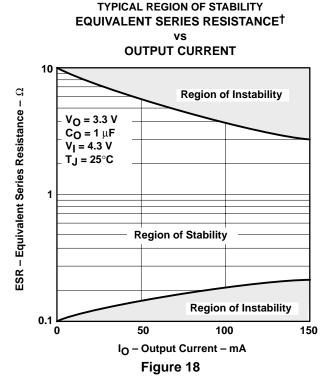


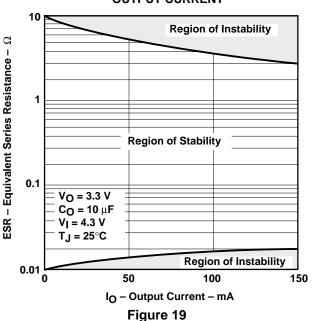
Figure 17. Test Circuit for Typical Regions of Stability (Figures 18 through 21) (Fixed Output Options)

SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

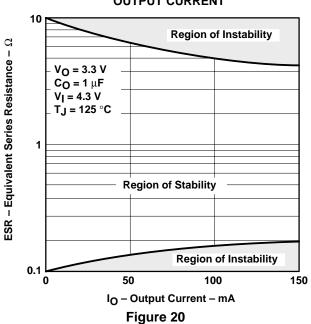
TYPICAL CHARACTERISTICS



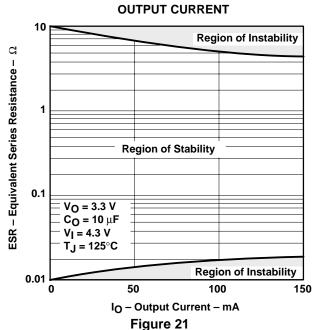
TYPICAL REGION OF STABILITY EQUIVALENT SERIES RESISTANCE[†] vs **OUTPUT CURRENT**



TYPICAL REGION OF STABILITY **EQUIVALENT SERIES RESISTANCE**[†] **OUTPUT CURRENT**



TYPICAL REGION OF STABILITY **EQUIVALENT SERIES RESISTANCE**[†] vs



[†] Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to Co.



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

APPLICATION INFORMATION

pin functions

enable (EN)

The $\overline{\mathsf{EN}}$ terminal is an input which enables or shuts down the device. If $\overline{\mathsf{EN}}$ is a logic high, the device will be in shutdown mode. When $\overline{\mathsf{EN}}$ goes to logic low, then the device will be enabled.

power good (PG) (TPS772xx)

The PG terminal is an open drain, active high output that indicates the status of V_{out} (output of the LDO). When V_{out} reaches 82% of the regulated voltage, PG will go to a high-impedance state. It will go to a low-impedance state when V_{out} falls below 82% (i.e. over load condition) of the regulated voltage. The open drain output of the PG terminal requires a pullup resistor

sense (SENSE)

The SENSE terminal of the fixed-output options must be connected to the regulator output, and the connection should be as short as possible. Internally, SENSE connects to a high-impedance wide-bandwidth amplifier through a resistor-divider network and noise pickup feeds through to the regulator output. It is essential to route the SENSE connection in such a way to minimize/avoid noise pickup. Adding RC networks between the SENSE terminal and V_{out} to filter noise is not recommended because it may cause the regulator to oscillate.

feedback (FB)

FB is an input terminal used for the adjustable-output options and must be connected to an external feedback resistor divider. The FB connection should be as short as possible. It is essential to route it in such a way to minimize/avoid noise pickup. Adding RC networks between FB terminal and V_{out} to filter noise is not recommended because it may cause the regulator to oscillate.

reset (RESET) (TPS771xx)

The RESET terminal is an open drain, active low output that indicates the status of V_{out}. When V_{out} reaches 95% of the regulated voltage, RESET will go to a high-impedance state after a 220-ms delay. RESET will go to a low-impedance state when V_{out} is below 95% of the regulated voltage. The open-drain output of the RESET terminal requires a pullup resistor.



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

APPLICATION INFORMATION

external capacitor requirements

An input capacitor is not usually required; however, a bypass capacitor (0.047 μ F or larger) improves load transient response and noise rejection if the TPS771xx or TPS772xx is located more than a few inches from the power supply. A higher-capacitance capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

Most low noise LDOs require an external capacitor to further reduce noise. This will impact the cost and board space. The TPS771xx and TPS772xx have very low noise specification requirements without using any external components.

Like all low dropout regulators, the TPS771xx or TPS772xx requires an output capacitor connected between OUT (output of the LDO) and GND (signal ground) to stabilize the internal control loop. The minimum recommended capacitance value is 1 μ F provided the ESR meets the requirement in Figures 19 and 21. In addition, a low-ESR capacitor can be used if the capacitance is at least 10 μ F and the ESR meets the requirements in Figures 18 and 20. Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described previously.

Ceramic capacitors have different types of dielectric material with each exhibiting different temperature and voltage variation. The most common types are X5R, X7R, Y5U, Z5U, and NPO. The NPO type ceramic type capacitors are generally the most stable over temperature. However, the X5R and X7R are also relatively stable over temperature (with the X7R being the more stable of the two) and are therefore acceptable to use. The Y5U and Z5U types provide high capacitance in a small geometry, but exhibit large variations over temperature; therefore, the Y5U and Z5U are not generally recommended for use on this LDO. Independent of which type of capacitor is used, one must make certain that at the worst case condition the capacitance/ESR meets the requirement specified in Figures 18 – 21.



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

APPLICATION INFORMATION

Figure 22 shows the output capacitor and its parasitic impedances in a typical LDO output stage.

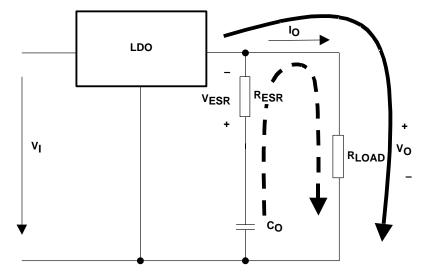


Figure 22. LDO Output Stage With Parasitic Resistances ESR and ESL

In steady state (dc state condition), the load current is supplied by the LDO (solid arrow) and the voltage across the capacitor is the same as the output voltage ($V_{Cout} = V_{out}$). This means no current is flowing into the C_{out} branch. If I_{out} suddenly increases (transient condition), the following occurs:

- The LDO is not able to supply the sudden current need due to its response time (t₁ in Figure 23). Therefore, capacitor C_{out} provides the current for the new load condition (dashed arrow). C_{out} now acts like a battery with an internal resistance, ESR. Depending on the current demand at the output, a voltage drop will occur at R_{ESR}. This voltage is shown as V_{ESR} in Figure 22.
- When C_{out} is conducting current to the load, initial voltage at the load will be V_{out} = V_{Cout} V_{ESR}. Due to the discharge of C_{out}, the output voltage V_{out} will drop continuously until the response time t₁ of the LDO is reached and the LDO will resume supplying the load. From this point, the output voltage starts rising again until it reaches the regulated voltage. This period is shown as t₂ in Figure 23.

The figure also shows the impact of different ESRs on the output voltage. The left brackets show different levels of ESRs where number 1 displays the lowest and number 3 displays the highest ESR.

From above, the following conclusions can be drawn:

- The higher the ESR, the larger the droop at the beginning of load transient.
- The smaller the output capacitor, the faster the discharge time and the bigger the voltage droop during the LDO response period.

SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

APPLICATION INFORMATION

conclusion

To minimize the transient output droop, capacitors must have a low ESR and be large enough to support the minimum output voltage requirement.

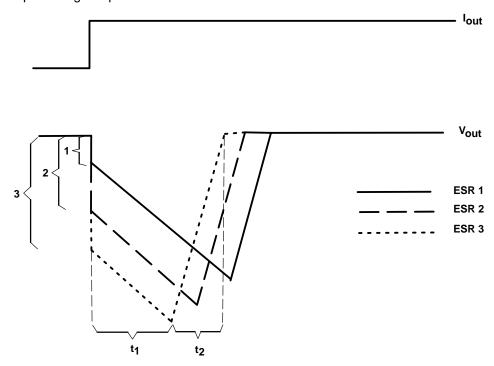


Figure 23. Correlation of Different ESRs and Their Influence to the Regulation of V_{out} at a Load Step From Low-to-High Output Current

SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

APPLICATION INFORMATION

programming the TPS77x01 adjustable LDO regulator

The output voltage of the TPS77x01 adjustable regulator is programmed using an external resistor divider as shown in Figure 24. The output voltage is calculated using:

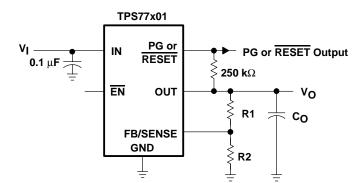
$$V_{O} = V_{ref} \times \left(1 + \frac{R1}{R2}\right) \tag{1}$$

Where:

 $V_{ref} = 1.1834 \text{ V}$ typ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately 50- μ A divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided, as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose R2 = $30.1 \text{ k}\Omega$ to set the divider current at $50 \text{ }\mu\text{A}$ and then calculate R1 using:

$$R1 = \left(\frac{V_{O}}{V_{ref}} - 1\right) \times R2 \tag{2}$$



OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	33.5	30.1	kΩ
3.3 V	53.8	30.1	kΩ
3.6 V	61.5	30.1	kΩ

NOTE: To reduce noise and prevent oscillation, R1 and R2 need to be as close as possible to the FB/SENSE terminal.

Figure 24. TPS77x01 Adjustable LDO Regulator Programming



SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

APPLICATION INFORMATION

regulator protection

The TPS771xx or TPS772xx PMOS-pass transistor has a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS771xx or TPS772xx also features internal current limiting and thermal protection. During normal operation, the TPS771xx or TPS772xx limits output current to approximately 0.9 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C(typ), thermal-protection circuitry shuts it down. Once the device has cooled below 130°C(typ), regulator operation resumes.

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125° C; the maximum junction temperature should be restricted to 125° C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_{D} , which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{J}max - T_{A}}{R_{\theta, JA}}$$

Where:

T_.Imax is the maximum allowable junction temperature.

 $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, i.e., 266.2°C/W for the 8-terminal MSOP with no airflow.

T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$P_{D} = (V_{I} - V_{O}) \times I_{O}$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.

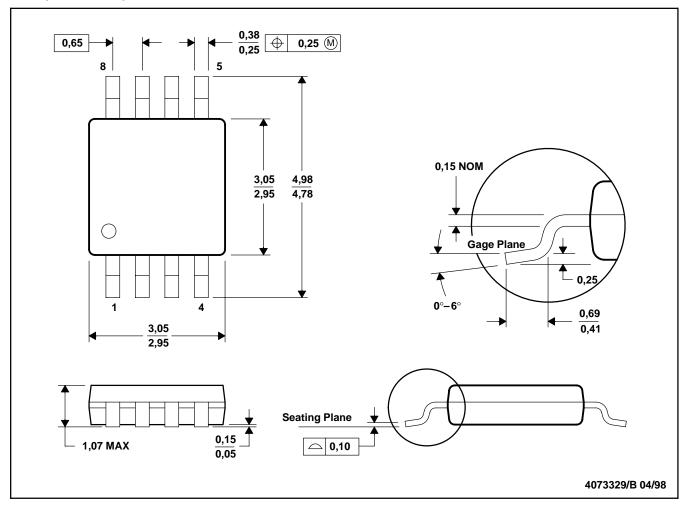


SLVS225D - FEBRUARY 2000 - REVISED OCTOBER 2000

MECHANICAL DATA

DGK (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion.
 - D. Falls within JEDEC MO-187





24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TPS77101DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFN	Samples
TPS77101DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFN	Samples
TPS77101DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFN	Samples
TPS77101DGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFN	Samples
TPS77115DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFO	Samples
TPS77115DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFO	Samples
TPS77115DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFO	Samples
TPS77115DGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFO	Samples
TPS77118DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFP	Samples
TPS77118DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFP	Samples
TPS77127DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFR	Samples
TPS77127DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFR	Samples
TPS77127DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFR	Samples
TPS77127DGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFR	Samples
TPS77128DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFS	Samples
TPS77128DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFS	Samples
TPS77133DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFU	Samples



24-Jan-2013



www.ti.com

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TPS77133DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFU	Samples
TPS77133DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFU	Samples
TPS77133DGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFU	Samples
TPS77150DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFV	Samples
TPS77150DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFV	Samples
TPS77150DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFV	Samples
TPS77150DGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFV	Samples
TPS77201DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFW	Samples
TPS77201DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFW	Samples
TPS77201DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFW	Samples
TPS77201DGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFW	Samples
TPS77215DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFX	Samples
TPS77215DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFX	Samples
TPS77218DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFY	Samples
TPS77218DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AFY	Samples
TPS77227DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AGA	Samples
TPS77227DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AGA	Samples
TPS77233DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AGD	Samples

www.ti.com

PACKAGE OPTION ADDENDUM

24-Jan-2013

Orderable Device	Status	Package Type	_		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
TPS77233DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AGD	Samples
TPS77250DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AGE	Samples
TPS77250DGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AGE	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS77101:

Automotive: TPS77101-Q1





24-Jan-2013

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
		Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ſ	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS77101DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS77115DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS77127DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS77133DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS77150DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS77201DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

www.ti.com 26-Jan-2013



*All dimensions are nominal

All difficultions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS77101DGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TPS77115DGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TPS77127DGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TPS77133DGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TPS77150DGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TPS77201DGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors <u>www.ti.com/omap</u> TI E2E Community <u>e2e.ti.com</u>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>